

Superconductor-insulator transitions and insulators with localized pairs

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Two experiments are described which are related to the problem of localized Cooper pairs. Magnetic-field-tuned superconductor-insulator transition was studied in amorphous In_2O_x with onset of the superconducting transition in zero field near 2 K. Experiments performed in the temperature range $T > 0.3$ K indicate that at the critical field, $B = B_c$, the first derivative of the resistance dR/dT is non-zero at $T = 0$ and hence the scaling relations should be written in more general form. Study of the magnetotransport of high-resistance metastable alloy CdSb on the insulating side of the superconductor-insulator transition revealed below 0.1 K a shunting conduction mechanism in addition to usual one-particle hopping. Possibility of pair hopping is discussed.

Among various scenarios of superconductor-insulator transitions (SIT) there exists a specific one proposed by Fisher¹: a field-induced and field-tuned transition in two-dimensional superconductors. It supposes, at $T = 0$, existence of delocalized Cooper pairs and localized vortices (superconductor) below the transition, at fields $B < B_c$, and of localized pairs and delocalized vortices (insulator) above it, at $B > B_c$. Several experimental studies^{2,3} apparently support this model describing the experimental data near the transition in terms of scaling relations¹. As a consequence of the approach^{1,3}, an insulator should be supposed to exist with localized Cooper pairs and with structured into vortices magnetic field. Properties of such insulator still have not been addressed. However, some experimental observations do point to localized pairs⁴. In particular, negative magnetoresistance in some three-dimensional materials, when superconductivity is alternated by insulating behavior, is one of such indications⁵. This negative magnetoresistance results from destroying by the magnetic field of the gap in the spectrum of localized electrons, which affects the single-particle tunneling⁶.

Still, our knowledge of localized pairs is rather poor and additional experimental observations are desired. In this study, two experiments are described, both related to the problem. First, the existence of the scaling variable¹

$$x = (B - B_c)T^{1/y} \quad (1)$$

is reexamined by analyzing magnetotransport in amorphous In_2O_x films⁷ (y is the product of two critical exponents from the theory¹). The existing studies leave some doubts. The amorphous MoGe films from³ display only 5% increase of the resistance on ten-fold decrease in temperature in high-magnetic-field limit and behave not like an insulator, but more like a metal with a small quantum correction to the resistance. The measurements with In_2O_x were made in quasireentrant region (see below, next section). Our measurements do not reject the possibility of the field-induced phase transition but lead to more general scaling relations.

The problem can be approached from another side, by looking for phenomena which would reveal existence of localized pairs in insulators. To that purpose, transport properties of the high-resistance metastable insulating alloy CdSb were studied⁸ where localized pairs were supposed to exist. This experiment is described in the last section of the paper.

In {O} | SCALING RELATIONS ⁷

There are two main types for the sets of 2D field-tuned SIT $R(T)$ curves. They differ in the behavior below the transition onset temperature T_{c0} (Fig.1). The first type is more complicate. In fields weak enough, the curves are maximum near T_{c0} and below go monotonously down, with positive first derivative, until the resistance R reaches zero (if at all). In fields strong enough, the first derivative is negative everywhere. And there is an intermediate field range with two extrema on the curves $R(T)$: a maximum at $T_{max} < T_{c0}$ and a minimum at a lower temperature. The latter separates from the maximum and shifts to lower T with decreasing field.

The second type is simpler. There is no intermediate field range and no curves with minimum at all; the rise in the field results in the shift of the maximum to lower T until it disappears. The authors of⁹, basing on their results obtained with ultrathin films of metals, consider the second type as an ideal one and attribute the low-temperature minimum (the so-called 'quasireentrant transition') to inhomogeneities and to one-particle tunneling between superconducting grains.

Amorphous In_2O_x films described in⁷ revealed the behavior of the first type, amorphous MoGe films³ of the second type. The scaling variable (1) proved to work in both cases. Both experiments had one feature in common: the films had low T_{c0} values, below 0.3 K. As T_{c0} seems to be the main energy which determines the scale for the

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problem, one should expect to get similar scaling relations with \ln s of higher T_{c0} in higher range of temperatures. We checked this in experiments with amorphous $\ln(0.1\text{ nm s } 200\text{ \AA thick})$. The value of T_{c0} in such \ln s depends on the oxygen content and hence on the heat treatment^{5,6}. We encountered \ln s of both types. In Fig.1 examples are presented with two \ln s brought by corresponding heat treatment to close values of T_{c0} . Below we shall present a detailed analysis for a \ln of the second type only since it is supposed to be more homogeneous⁹.

The analysis in^{2,3} started with determining the values of the critical field B_c and of the critical resistance R_c by using the condition

$$\left(\frac{dR}{dT}\right)_{B_c} = 0 \quad (2)$$

at the lowest temperature and assuming that isomagnetic curve at B_c remained zero-slope till $T = 0$. We did not have a horizontal curve in our fan, Fig.2. Hence, instead, we marked maxima on the curves $R(T)$ and, utilizing linear relation between maximum values R_{max} and their positions, extrapolated the function $R_{max}(T)$ to $T = 0$ and got the limiting R_c value (dashed line in Fig.2). One of the curves of the fan in Fig.2, the curve obtained at $B = 5\text{ T}$ looks like a straight line; it separates curves with positive second derivative from curves with negative derivative. Extrapolated to zero temperature (dotted line), it comes practically to the same point R_c . This gives us grounds to claim that, inspite we remain rather far in temperature from the supposed transition, at $T > 0.3\text{ K}$, we can determine the critical parameters in the state in question of our sample from Fig.2:

$$B_c = 5\text{ T}; \quad R_c = 8\text{ k}\Omega\text{ m}; \quad (3)$$

In essence, we have assumed that not the first but the second derivative is zero at the transition point; the first derivative remains finite and the line which separates on the $(T; R)$ -plane two Fisher phases, if they exist, has a finite slope. For this definite \ln the slope is

$$\left(\frac{dR}{dT}\right)_{B_c} = 0.83\text{ k}\Omega\text{ m / T}; \quad (4)$$

Next, we eliminate this slope by introducing a function

$$R' = R(T) - T \quad (5)$$

and check the scaling properties not of R but of R' . Plotting R' against the scaling variable $jB/B_c j = T^{1-y}$ we selected the power y to bring the data to the same curve, the critical field B_c being kept within 1% of the (3) value (Fig.3). The adjustment led to the same value of y , $y = 1.3$, which had been obtained in² and³. For an additional comparison, two scaling curves from³ for $R(T; B)$ normalized by $R_c = 8.1\text{ T}$ are reproduced in Fig.3.

Similar analysis was applied to the data for an amorphous $\ln(0.1\text{ nm})$ with the first type of behavior (Fig.1(a)). This time we used not maxima, but minima on the curves $R(T)$ and got the R_c value by extrapolation to $T = 0$ of the function $R_{min}(T)$. The main difference consisted in the sign of the slope. The deformed function $R'(T; B)$ after using the scaling variable (1) again collapsed onto two branches and even the value of y was obtained practically the same.

These results mean that the scaling relations¹ either should be generalized by replacing the \ln resistance R by R' from (5) or they are not very specific and hence not very crucial as a criterion of existence of the field-tuned phase transition.

Cd(Sb) | PAIR TUNNELING⁸

The main process which determines the low-temperature conductance in insulators is tunneling. Suppose that we have localized Cooper pairs. For an electron of a pair to hop, it has to "pay off" the binding energy. This introduces into conductivity additional exponential factor

$$\sigma_1(T) = \sigma_n \exp(-\Delta/T); \quad (6)$$

where σ_n is the expected conductivity at a temperature T in the absence of pairing. High enough magnetic field is assumed to destroy the pairing. The phenomenon can be recognized by negative magnetoresistance. Field eliminates the gap and makes the resistance $\exp(-\Delta/T)$ times smaller. In principle, measuring the ratio $\sigma(T) = \sigma_n(T) = \sigma_1(T)$ affords the possibility of extracting the gap. Such negative magnetoresistance caused by one-particle tunneling is well known in granular superconductors, both, in \ln s^{10,11} and bulk¹².

We attempted to measure the function $\sigma(T)$ on metastable Cd(Sb) alloy in a high-resistance state which was for sure insulating and still had negative magnetoresistance originated in superconductivity¹³. A sample of $\text{Cd}_{47}\text{Sb}_{53}$ alloy had

a rod-like form, with all dimensions amounting to several millimeters. The sample was transformed into a metallic phase, which is a superconductor with $T_{c0} = 4.5\text{ K}$, in a high-pressure chamber and, being retained in this state, was quenched to the liquid-nitrogen temperature. After cooling, the sample was clamped in a holder by two pairs of gold wires with pointed ends and placed into a cryostat. The low-temperature transport measurements were alternated with heating of the sample to room temperature. At room temperature, the material slowly transformed into a disordered-insulator state. The transformation was monitored by resistance measurements and could be interrupted by returning to the liquid-nitrogen temperature. The experimental procedure is described in detail in¹³.

The sample resistance R is in essence the averaged value, because in the course of the transformation the sample becomes inhomogeneous. According to Ref.¹⁴, below T_{c0} the sample looks like a mixture of different "weakly-superconducting" elements, such as tunnel junctions, constrictions, thin wires, etc. The density and scales of these elements change during transformation, leading to evolution of the sample behavior below T_{c0} ^{12;13}. We'll deal with the state in which the average sample resistance R has increased by five orders of magnitude comparing to the initial one, only a weak kink has remained on the curve $R(T)$ at $T = T_{c0}$ and the curve has negative derivative everywhere. The T_{c0} value while evolution to this state has slightly decreased down to 3.8 K .

The low temperature measurements were performed in an Oxford TLM-400 dilution refrigerator with a base temperature of 25 mK . A four-terminal lock-in technique at a frequency of 10 Hz was used. The ac current was equal to 1 nA and corresponded to the linear regime. The low-temperature part of the curve $R(T)$ is shown in Fig.4.

The experimental dependences of $(T;B) = R(T;B)/R(T;B = 4\text{ T})$ on magnetic field at different temperatures are presented in Fig.5. The magnetoresistance is negative and saturates in magnetic fields exceeding 2 T , bringing the value of ρ to unity. So, the resistance values at a field of 4 T , used for normalizing, are taken from the field-independent region. Note that $\rho(T) = \rho(T;0)$. In the temperature range between 490 and 190 mK the value of $\rho(T)$ increases with decreasing temperature, in qualitative agreement with Eq. (6) (inset to Fig.5). This corresponds to what has been observed previously at higher temperatures¹³. However, in the low-temperature limit the behavior of $\rho(T)$ changes drastically. It is maximum at a temperature of about 100 mK and then decreases with further lowering the temperature. In weak magnetic fields there appears an initial increase on the dependence. However, at any fixed magnetic field $B < 2\text{ T}$ the value of ρ behaves similarly (see inset to Fig.5). This contrasts sharply with the temperature dependence of the normal-state resistance which is monotonous in the range of temperatures used (see Fig.4).

The observed decrease of the ratio ρ with decreasing temperature unambiguously indicates that at low temperatures the conductivity σ_1 , which originates from single-particle tunneling, is shunted by conductivity σ_2 of another kind:

$$\sigma = \sigma_1(T) + \sigma_2; \quad (7)$$

We believe that σ_2 is due to incoherent pair tunneling (coherent, i.e. Josephson, pair tunneling is supposed to be absent in this insulating state; Probably the maximum of $\rho(B)$ at $B = 0.1\text{ T}$ at the lowest temperatures designates destroying by the magnetic fields of the remnants of the coherent scattering). The single-particle tunneling current i_1 is described in the first-order approximation by barrier transparency $t: i_1 / t \exp(-T) = T$. It is proportional to the product of two small factors, one of which is temperature dependent. Since the Cooper pairs are at the Fermi level, the two electrons forming a pair do not need to be excited above the gap for simultaneous tunneling. Hence i_2 / T^2 , without the exponential temperature-dependent factor. When the temperature is sufficiently low, so that

$$t > \exp(-T); \quad \text{i.e.,} \quad T < -j \ln t; \quad (8)$$

the single-particle tunneling is frozen out, and the two-particle tunneling current comes into play.

The two particles bound into a pair in the initial state may come to be unbound in the final state. Such process of pair tunneling looks similar to the two-particle contribution to the tunnel current through a superconductor { normal metal junction (SIN junction)¹⁵. The latter may prove to be very important in high-resistance granular superconductors.

CONCLUSION

Both experiments described above can be interpreted as confirmation of existence of localized pairs. But they do not give any information about how this localization is realized. The one-particle localization radius may turn to be either larger, or smaller than the coherence length ξ_{sc} . The case ξ_{sc} is an extreme limit of granular superconductors, with only one pair in a grain. The opposite case ξ_{sc} is assumed, for instance, in the model of localized bipolarons¹⁶. To distinguish these two possibilities, other experiments are required.

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FIG. 1. Temperature dependence of the resistance of two different amorphous $\text{In}_{1-x}\text{Sb}_x$ samples, both 200 Å thick, in various magnetic fields. Sets (a) and (b) represent two types of $\text{In}_x\text{Sb}_{1-x}$ behavior (see text)

FIG. 2. Central part of the set from Fig. 1 (b) represented in detail, with smaller field step. Experimental points are plotted only on one curve, those at $B = 5.0 \text{ T}$. Dashed line displays maxima values, $R_{\text{max}}(T)$ extrapolated to $T = 0$. Dotted line is linear extrapolation of data at the field $B = 5.0 \text{ T}$

FIG. 3. Scaling dependence of the renormalized resistance R^* for the $\text{In}_x\text{Sb}_{1-x}$ presented in Figs. 1 (b) and 2. Different symbols are used to distinguish the data in different fields. For comparison, the scaling function from Fig. 3 of Ref. 3 normalized by $R_0 = 8.1 \text{ k}\Omega$ is reproduced by solid lines

FIG. 4. Low-temperature dependence of the resistance of the $\text{Cd}_{1-x}\text{Sb}_x$ sample in the state under investigation illustrating its insulating behavior and negative magnetoresistance.

FIG. 5. Normalized magnetoresistance $R(T; B)$ of the $\text{Cd}_{1-x}\text{Sb}_x$ sample as a function of B at different temperatures. Inset: $R(T; B)$ as a function of T at two values of B ; $R(T; 0)$ (solid line), $R(T)$ (dashed line)









